

Phosphole-based π -conjugated materials for OLEDs

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Table S1. Crystal data and structure refinement for derivative **3b** after the ‘squeeze’ treatment.

molecular formula	C ₄₄ H ₃₉ Au Cl P
molecular weight, g/mol	831.14
a, Å	11.2536(9)
b, Å	25.600(3)
c, Å	13.7924(14)
a, deg	90
b, deg	98.022(3)
g, deg	90
V, Å ³	3934.6(7)
Z	4
D _{calc} , g cm ⁻³	1.403
crystal system	Monoclinic
space group	P2 ₁ /n
T, K	100(2)
wavelength Mo Ka, Å	0.71073
m, mm ⁻¹	3.875
F(000)	1656
θ limit, deg	1.59 - 26.56
no. reflns collected	31372
no. ind reflns	8060
reflections [I > 2s(I)]	6332
data/restraints/parameters	8060 / 0 / 424
GOF on F ²	1.036
final R indices	R1 = 0.0461
[I > 2s(I)]	wR2 = 0.1266
largest diff peak	2.284
and hole (e Å ⁻³)	2.284 -2.328

Table S2. Crystal data and structure refinement for derivative **3b** before the ‘squeeze’ treatment.

molecular formula	C45 H41 Au Cl3 P
molecular weight, g/mol	916.06
α , Å	11.2536(9)
β , Å	25.600(3)
χ , Å	13.7924(14)
α , deg	90
β , deg	98.022(3)
γ , deg	90
V, Å ³	3934.6(7)
Z	4
D _{calc} , g cm ⁻³	1.543
crystal system	Monoclinic
space group	P21/n
T, K	100(2)
wavelength Mo Ka, Å	0.71073
μ , mm ⁻¹	4.014
F(000)	1824
θ limit, deg	1.59 - 26.56
no. reflns collected	31372
no. ind reflns	8060
reflections [I > 2 σ (I)]	6323
data/restraints/parameters	8060 / 0 / 469
GOF on F ²	1.092
final R indices	R1 = 0.0524
[I > 2 σ (I)]	wR2 = 0.1347
largest diff peak and hole (e Å ⁻³)	2.175 -2.430

Table S3 : Electrochemical data for **3a,b**, **4a,b** and **R_{AuCl}/Rs** (vs. SCE)

Compounds	E_{ox}/V^a	E_{ox}^{onset}/V	E_{red}/V^a	E_{red}^{onset}/V	HOMO/eV ^b	LUMO/eV ^c	DE ^{El} /eV ^d
3a	+ 1.47	+ 1.26	-1.55	- 1.47	- 5.66	- 2.93	2.73
3b	+ 1.37	+ 1.28	-1.58	- 1.51	- 5.68	- 2.89	2.79
4a	+ 1.38	+ 1.18	-1.60	- 1.47	- 5.58	- 2.93	2.65
4b	+ 1.32	+ 1.12	-1.56	- 1.52	- 5.52	- 2.88	2.64
A	+ 1.95	+ 1.40	-1.64	- 1.60	- 5.80	- 2.80	3.00
B	+ 1.62	+ 1.37	-1.58	- 1.61	- 5.77	- 2.79	2.98

^aAll potentials were obtained during cyclic voltametric investigations in 0.2 M Bu₄NPF₆ in CH₂Cl₂. Platinum electrode diameter 1 mm, sweep rate: 200 mV s⁻¹. ^b Calculated from the onset oxidation potential E_{ox}^{onset}/V . ^c Calculated from the onset reduction potential E_{red}^{onset}/V . ^d Calculated as DE^{El} = HOMO-LUMO from the redox data.

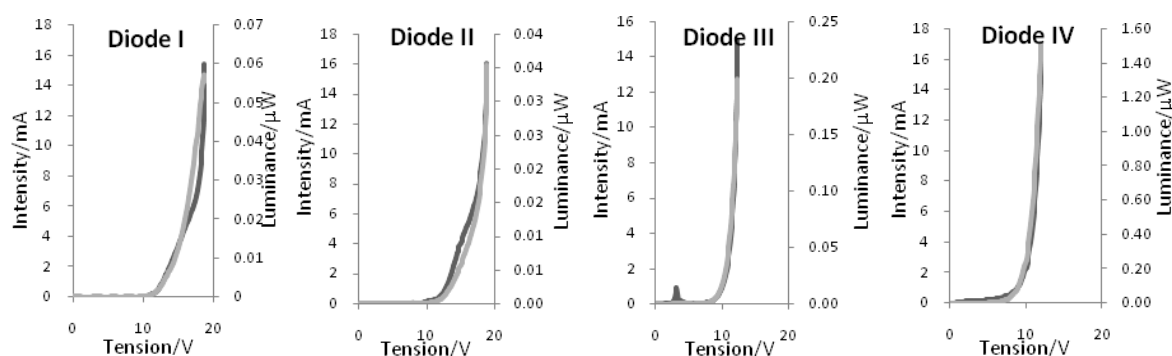


Figure S1 I-V-L characteristics of diodes I-IV.

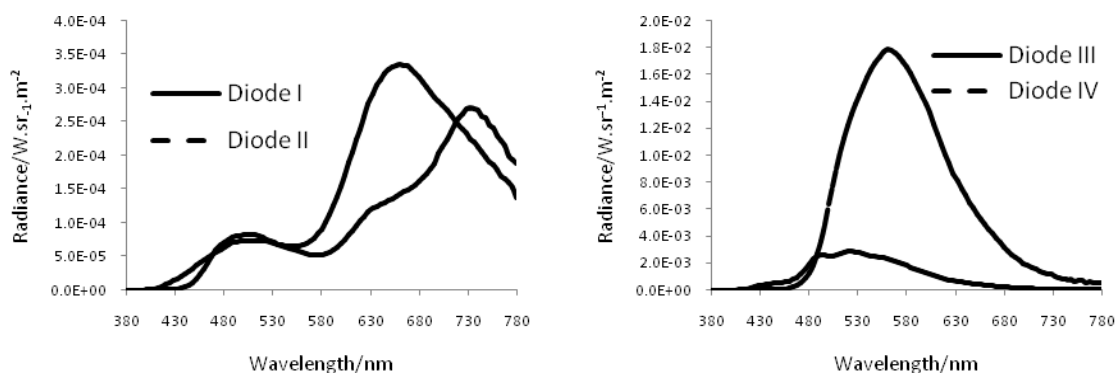


Figure S2 EL spectra of the devices I-IV recorded at 30 mA/cm².

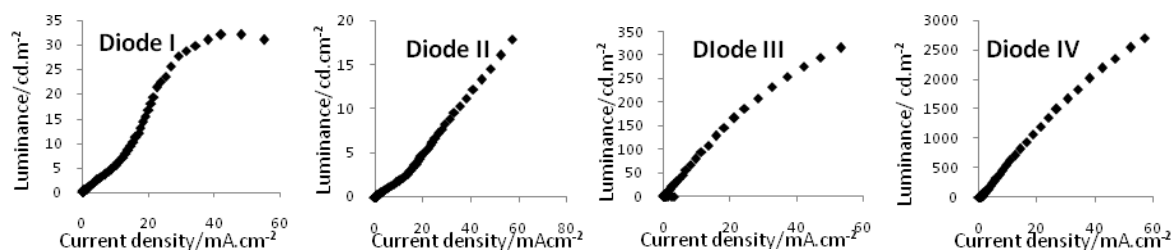


Figure S3 Luminance-current density characteristics of diodes I-IV

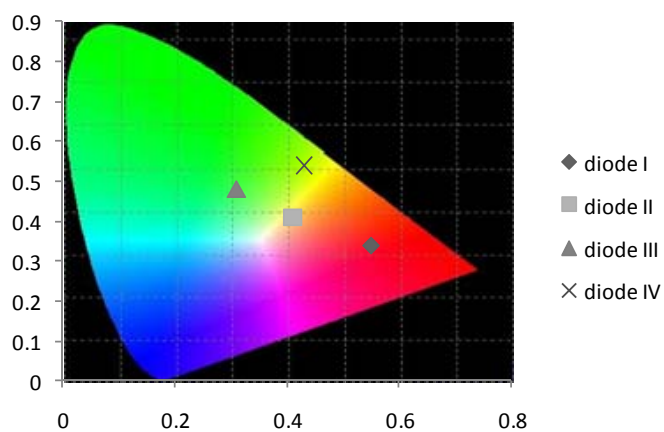


Figure S4 CIE coordinates of diodes I-IV.

Compounds	Diodes		$B_1^a/\text{cd.m}^{-2}$	$B_1^b/\text{cd.m}^{-2}$
4a	III	1	28.4	21.1
		2	23.6	17.0
		3	26.2	20.6
4b	IV	1	120.1	114.3
		2	118.9	110.5
		3	109.4	97.6

^a brightness at 1 mA, measured before IVL measurement; ^b brightness at 1 mA, measured after IVL measurement

Figure S5 Measurements of the Brightness at 1 mA before and after IVL Characterizations